



SDM1100S1F

SURFACE MOUNT SCHOTTKY BARRIER DIODE

Product Summary

V _{RRM} (V)	I _O (A)	V _{F(MAX)} (V) @+25°C	I _{R(MAX)} (μΑ) @+25°C
100	1.0	0.82	5

Description and Applications

The device is a single rectifier packaged in SOD123F (Type B). Offering low V_F and excellent high temperature stability this device is ideal for use in general rectification applications as a:

- Boost Diode
- Blocking Diode

Features and Benefits

- Low forward voltage (V_F) minimizes conduction losses and improving efficiency
- Reduced High Temperature Reverse Leakage; Increased Reliability against Thermal Runaway Failure in High Temperature Operation
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOD123F (Type B)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Polarity: Cathode Band
- Weight: 0.015 grams (Approximate)

SOD123F (Type B)





Top View

Bottom View

Ordering Information (Note 4)

Part Number	Case	Packaging
SDM1100S1F-7	SOD123F (Type B)	3000/Tape & Reel

Notes:

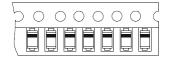
- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



DA = Product Type Marking Code YM = Date Code Marking Y = Year (ex.: C = 2015)

M = Month (ex.: 9 = September)



Date Code Key

Year	2013	2014	2015	2016	2017	2018	2019	2020
Code	Α	В	С	D	Е	F	G	Н

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	100	V
Average Rectified Output Current	lo	1	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	50	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	135	°C/W
Typical Thermal Resistance, Junction to Case (Note 5)	$R_{ heta JC}$	20	°C/W
Typical Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	85	°C/W
Typical Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	12	°C/W
Operating Junction Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	$V_{(BR)R}$	100	_	_	V	$I_R = 1.0 \text{mA}$
Forward Voltage Drop	V _F	_ _ _	0.75 0.81 0.60	0.82 — —	V	$I_F = 1A$, $T_J = +25$ °C $I_F = 2A$, $T_J = +25$ °C $I_F = 1A$, $T_J = +125$ °C
Leakage Current (Note 7)	I _R		0.15 0.110	5 5	μA mA	$V_R = 100V, T_J = +25^{\circ}C$ $V_R = 100V, T_J = +125^{\circ}C$
Total Capacitance	Ст	_	28	_	pF	$V_R = 4V$, $f = 1MHz$

Notes:

- 5. Device mounted on 1 x MRP FR-4 PC board, 2oz.
- S. Device mounted on 1 inch sq. copper pad, 2oz.
 Short duration pulse test used to minimize self-heating effect.

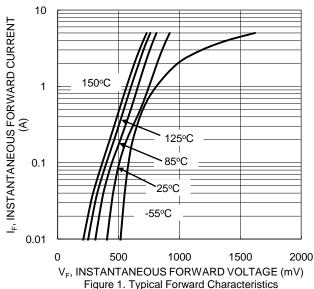
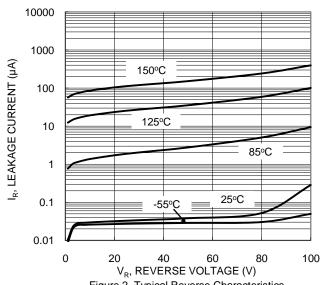
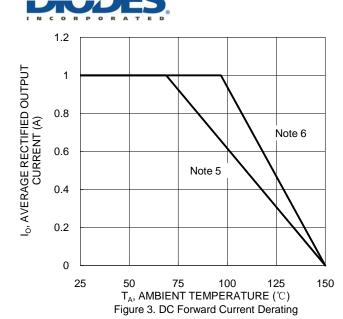
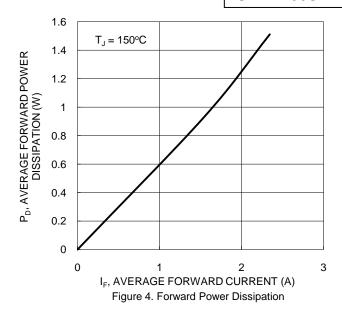
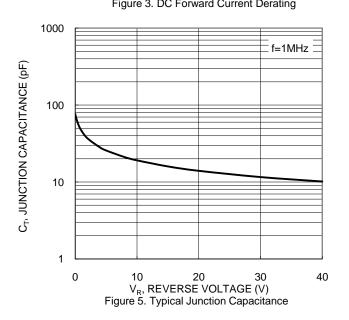


Figure 1. Typical Forward Characteristics





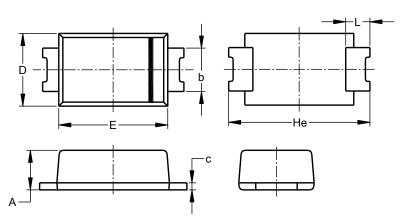




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOD123F (Type B)



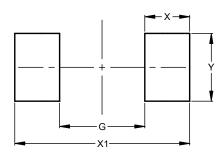
S	SOD123F (Type B)							
Dim	Min	Max	Тур					
Α	0.81	1.15						
b	0.80	1.35						
С	0.05	0.30						
D	1.70	1.90	1.80					
Е	2.60	2.80	2.70					
He	3.30	3.70	3.50					
L	0.35	0.85						
All	Dimen	sions	in mm					



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOD123F (Type B)



Dimensions	Value (in mm)
G	1.90
Х	1.00
X1	3.90
Υ	1.50

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